

### **SI3424BDV-T1-GE3**

#### SI3424BDV-T1-GE3 Information

|                  | Part Number  | SI3424BDV-T1-GE3  |
|------------------|--------------|---|
|                  | Manufacturer | Vishay Siliconix  |
|                  | Category     | Discrete Semiconductor Products<br>Transistors - FETs, MOSFETs - Single |
|                  | Description  | MOSFET N-CH 30V 8A 6TSOP  |
|                  | Package      | SOT-23-6 Thin, TSOT-23-6  |
|                  |              | For the pricing/inventory/lead time, please contact                     |
| r Reference Only |              | us<br>Website: https://www.heisener.com                                 |

E-mail: salesdept@heisener.com



Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



#### SI3424BDV-T1-GE3 Specifications

| Manufacturer Part Number               | SI3424BDV-T1-GE3                     |
|--|--------------------------------------|
| Manufacturer                           | Vishay Siliconix                     |
| Category                               | Discrete Semiconductor Products      |
|  | Transistors - FETs, MOSFETs - Single |
| Package                                | SOT-23-6 Thin, TSOT-23-6             |
| Series                                 | TrenchFET?                           |
| FET Type                               | N-Channel                            |
| Technology                             | MOSFET (Metal Oxide)                 |
| Drain to Source Voltage (Vdss)         | 30V                                  |
| Current - Continuous Drain (Id) @ 25°C | 8A (Tc)                              |
| Drive Voltage (Max Rds On, Min Rds On) | 4.5V, 10V                            |
| Vgs(th) (Max) @ Id                     | 3V @ 250µA                           |
| Gate Charge (Qg) (Max) @ Vgs           | 19.6nC @ 10V                         |
| Input Capacitance (Ciss) (Max) @ Vds   | 735pF @ 15V                          |
| Vgs (Max)                              | $\pm 20 V$                           |
| FET Feature                            | -                                    |
| Power Dissipation (Max)                | 2.1W (Ta), 2.98W (Tc)                |
| Rds On (Max) @ Id, Vgs                 | 28 mOhm @ 7A, 10V                    |
| Operating Temperature                  | -55°C ~ 150°C (TJ)                   |
| Mounting Type                          | Surface Mount                        |
| Supplier Device Package                | 6-TSOP                               |
| Package / Case                         | SOT-23-6 Thin, TSOT-23-6             |
|  | Report errors?                       |

#### SI3424BDV-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE BUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### SI3424BDV-T1-GE3 Payment Methods





If you have any question about SI3424BDV-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com